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Details

Product Status	Obsolete
Core Processor	XC800
Core Size	8-Bit
Speed	24MHz
Connectivity	CANbus, SSI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	34
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1.75K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 8x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	PG-TQFP-48
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/saf-xc886cm-8ffi-3v3-ac

General Device Information

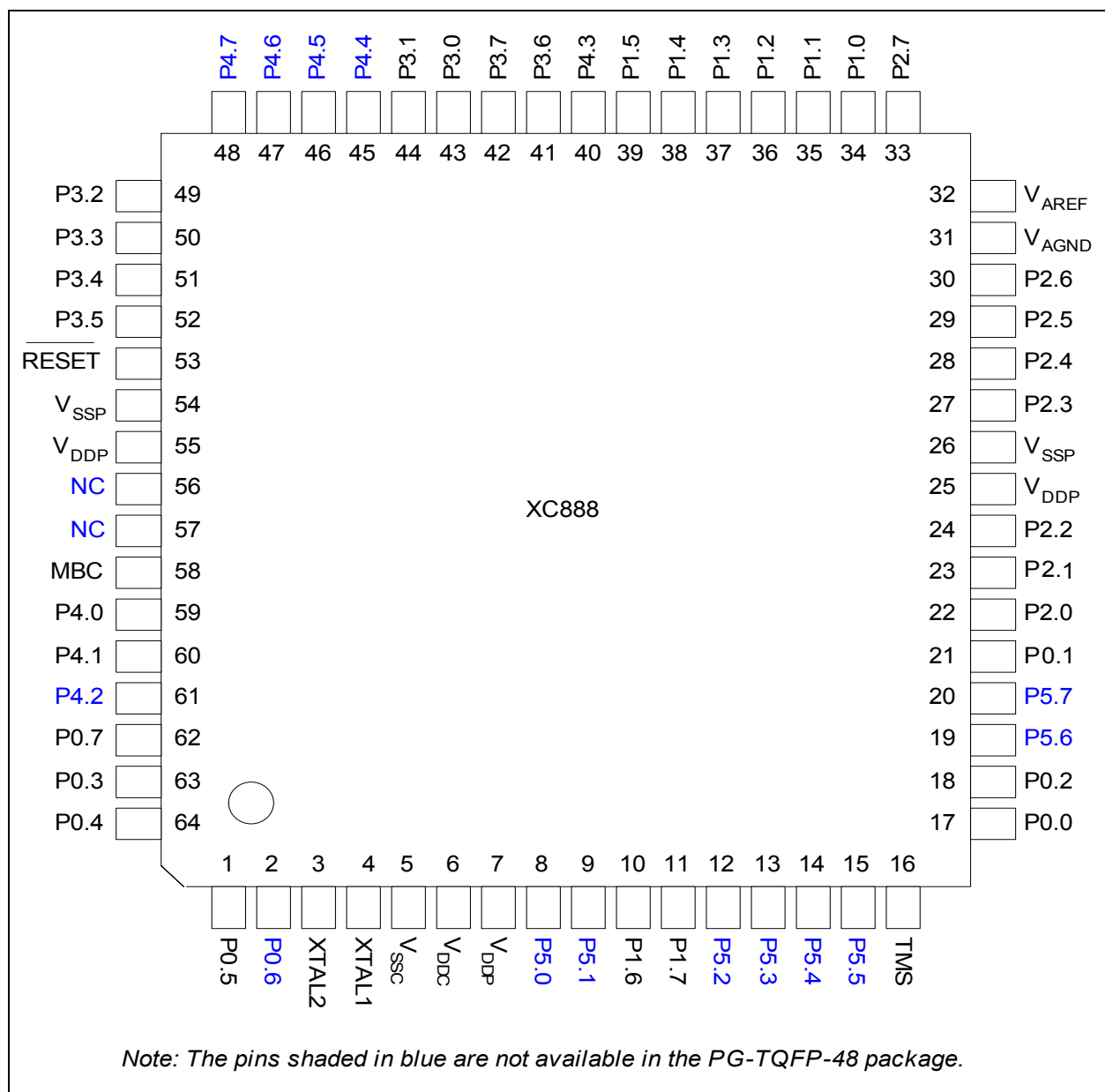


Figure 5 XC888 Pin Configuration, PG-TQFP-64 Package (top view)

Functional Description

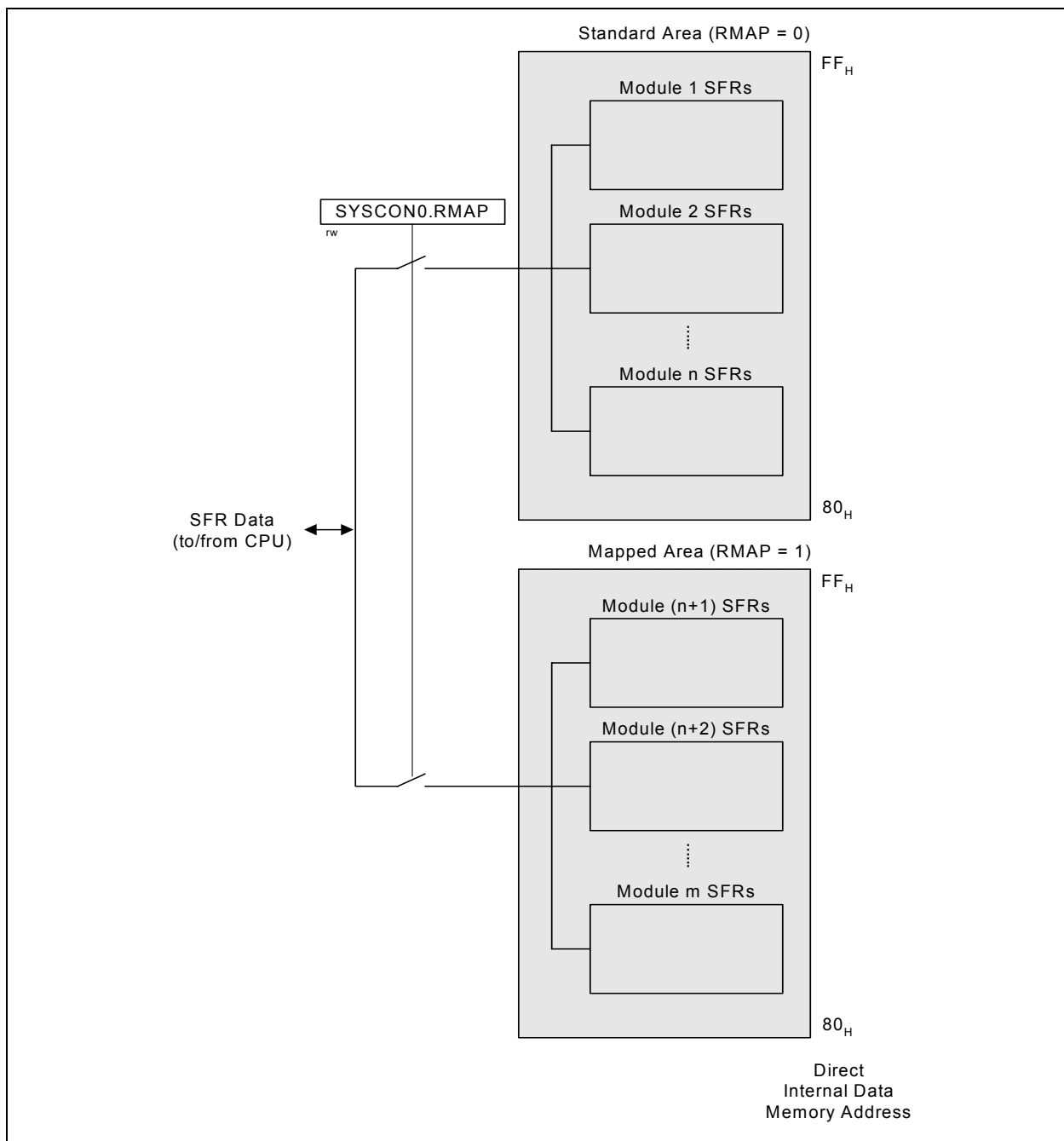


Figure 8 Address Extension by Mapping

Functional Description

SYSCON0

System Control Register 0

Reset Value: 04_H

7	6	5	4	3	2	1	0
0			IMODE	0	1	0	RMAP
r			rw	r	r	r	rw

Field	Bits	Type	Description
RMAP	0	rw	Interrupt Node XINTR0 Enable 0 The access to the standard SFR area is enabled 1 The access to the mapped SFR area is enabled
1	2	r	Reserved Returns 1 if read; should be written with 1.
0	[7:5], 3,1	r	Reserved Returns 0 if read; should be written with 0.

Note: The RMAP bit should be cleared/set by ANL or ORL instructions.

3.2.2.2 Address Extension by Paging

Address extension is further performed at the module level by paging. With the address extension by mapping, the XC886/888 has a 256-SFR address range. However, this is still less than the total number of SFRs needed by the on-chip peripherals. To meet this requirement, some peripherals have a built-in local address extension mechanism for increasing the number of addressable SFRs. The extended address range is not directly controlled by the CPU instruction itself, but is derived from bit field PAGE in the module page register MOD_PAGE. Hence, the bit field PAGE must be programmed before accessing the SFR of the target module. Each module may contain a different number of pages and a different number of SFRs per page, depending on the specific requirement. Besides setting the correct RMAP bit value to select the SFR area, the user must also ensure that a valid PAGE is selected to target the desired SFR. A page inside the extended address range can be selected as shown in [Figure 9](#).

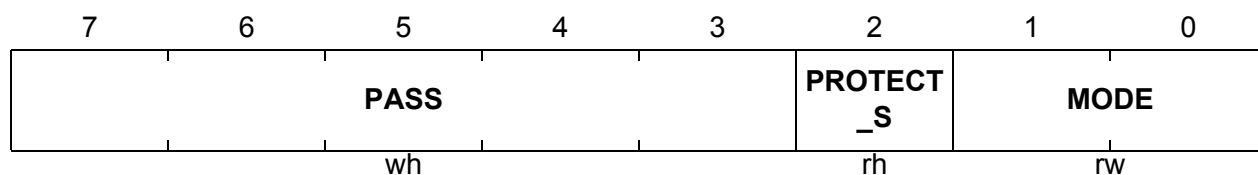
Functional Description

3.2.3.1 Password Register

PASSWD

Password Register

Reset Value: 07_H



Field	Bits	Type	Description
MODE	[1:0]	rw	Bit Protection Scheme Control Bits 00 Scheme disabled - direct access to the protected bits is allowed. 11 Scheme enabled - the bit field PASS has to be written with the passwords to open and close the access to protected bits. (default) Others: Scheme Enabled. These two bits cannot be written directly. To change the value between 11 _B and 00 _B , the bit field PASS must be written with 11000 _B ; only then, will the MODE[1:0] be registered.
PROTECT_S	2	rh	Bit Protection Signal Status Bit This bit shows the status of the protection. 0 Software is able to write to all protected bits. 1 Software is unable to write to any protected bits.
PASS	[7:3]	wh	Password Bits The Bit Protection Scheme only recognizes three patterns. 11000 _B Enables writing of the bit field MODE. 10011 _B Opens access to writing of all protected bits. 10101 _B Closes access to writing of all protected bits

Functional Description
Table 5 CPU Register Overview (cont'd)

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
A8 _H	IEN0 Reset: 00 _H Interrupt Enable Register 0	Bit Field	EA	0	ET2	ES	ET1	EX1	ET0	EX0
		Type	rw	r	rw	rw	rw	rw	rw	rw
B8 _H	IP Reset: 00 _H Interrupt Priority Register	Bit Field	0		PT2	PS	PT1	PX1	PT0	PX0
		Type	r		rw	rw	rw	rw	rw	rw
B9 _H	IPH Reset: 00 _H Interrupt Priority High Register	Bit Field	0		PT2H	PSH	PT1H	PX1H	PT0H	PX0H
		Type	r		rw	rw	rw	rw	rw	rw
D0 _H	PSW Reset: 00 _H Program Status Word Register	Bit Field	CY	AC	F0	RS1	RS0	OV	F1	P
		Type	rwh	rwh	rw	rw	rw	rwh	rw	rh
E0 _H	ACC Reset: 00 _H Accumulator Register	Bit Field	ACC7	ACC6	ACC5	ACC4	ACC3	ACC2	ACC1	ACC0
		Type	rw	rw	rw	rw	rw	rw	rw	rw
E8 _H	IEN1 Reset: 00 _H Interrupt Enable Register 1	Bit Field	ECCIP 3	ECCIP 2	ECCIP 1	ECCIP 0	EXM	EX2	ESSC	EADC
		Type	rw	rw	rw	rw	rw	rw	rw	rw
F0 _H	B Reset: 00 _H B Register	Bit Field	B7	B6	B5	B4	B3	B2	B1	B0
		Type	rw	rw	rw	rw	rw	rw	rw	rw
F8 _H	IP1 Reset: 00 _H Interrupt Priority 1 Register	Bit Field	PCCIP 3	PCCIP 2	PCCIP 1	PCCIP 0	PXM	PX2	PSSC	PADC
		Type	rw	rw	rw	rw	rw	rw	rw	rw
F9 _H	IPH1 Reset: 00 _H Interrupt Priority 1 High Register	Bit Field	PCCIP 3H	PCCIP 2H	PCCIP 1H	PCCIP 0H	PXMH	PX2H	PSSC H	PADC H
		Type	rw	rw	rw	rw	rw	rw	rw	rw

3.2.4.2 MDU Registers

The MDU SFRs can be accessed in the mapped memory area (RMAP = 1).

Table 6 MDU Register Overview

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
RMAP = 1										
B0 _H	MDUSTAT Reset: 00_H MDU Status Register	Bit Field	0					BSY	IERR	IRDY
		Type	r					rh	rwh	rwh
B1 _H	MDUCON Reset: 00_H MDU Control Register	Bit Field	IE	IR	RSEL	STAR T	OPCODE			
		Type	rw	rw	rw	rwh	rw			
B2 _H	MD0 Reset: 00_H MDU Operand Register 0	Bit Field	DATA							
		Type	rw							
B2 _H	MR0 Reset: 00_H MDU Result Register 0	Bit Field	DATA							
		Type	rh							
B3 _H	MD1 Reset: 00_H MDU Operand Register 1	Bit Field	DATA							
		Type	rw							

Functional Description

Table 7 CORDIC Register Overview (cont'd)

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
A0 _H	CD_STATC Reset: 00 _H CORDIC Status and Data Control Register	Bit Field	KEEP Z	KEEP Y	KEEP X	DMAP	INT_EN	EOC	ERROR	BSY
		Type	rw	rw	rw	rw	rw	rwh	rh	rh
A1 _H	CD_CON Reset: 00 _H CORDIC Control Register	Bit Field	MPS		X_USIGN	ST_MODE	ROTV EC	MODE		ST
		Type	rw		rw	rw	rw	rw		rwh

3.2.4.4 System Control Registers

The system control SFRs can be accessed in the mapped memory area (RMAP = 0).

Table 8 SCU Register Overview

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
RMAP = 0 or 1										
8F _H	SYSCON0 Reset: 04_H System Control Register 0	Bit Field	0			IMOD E	0	1	0	RMAP
		Type	r			rw	r	r	r	rw
RMAP = 0										
BF _H	SCU_PAGE Reset: 00_H Page Register	Bit Field	OP		STNR		0	PAGE		
		Type	w		w		r	rw		
RMAP = 0, PAGE 0										
B3 _H	MODPISEL Reset: 00_H Peripheral Input Select Register	Bit Field	0	URRIS H	JTAGT DIS	JTAGT CKS	EXINT 2IS	EXINT 1IS	EXINT 0IS	URRIS
		Type	r	rw	rw	rw	rw	rw	rw	rw
B4 _H	IRCON0 Reset: 00_H Interrupt Request Register 0	Bit Field	0	EXINT 6	EXINT 5	EXINT 4	EXINT 3	EXINT 2	EXINT 1	EXINT 0
		Type	r	rwh	rwh	rwh	rwh	rwh	rwh	rwh
B5 _H	IRCON1 Reset: 00_H Interrupt Request Register 1	Bit Field	0	CANS RC2	CANS RC1	ADCS R1	ADCS R0	RIR	TIR	EIR
		Type	r	rwh	rwh	rwh	rwh	rwh	rwh	rwh
B6 _H	IRCON2 Reset: 00_H Interrupt Request Register 2	Bit Field	0			CANS RC3	0			CANS RC0
		Type	r			rwh	r			rwh
B7 _H	EXICON0 Reset: F0_H External Interrupt Control Register 0	Bit Field	EXINT3		EXINT2		EXINT1		EXINT0	
		Type	rw		rw		rw		rw	
BA _H	EXICON1 Reset: 3F_H External Interrupt Control Register 1	Bit Field	0		EXINT6		EXINT5		EXINT4	
		Type	r		rw		rw		rw	
BB _H	NMICON Reset: 00_H NMI Control Register	Bit Field	0	NMI ECC	NMI VDDP	NMI VDD	NMI OCDS	NMI FLASH	NMI PLL	NMI WDT
		Type	r	rw	rw	rw	rw	rw	rw	rw

Functional Description

Table 14 CCU6 Register Overview (cont'd)

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
FA _H	CCU6_CC60SRL Reset: 00_H Capture/Compare Shadow Register for Channel CC60 Low	Bit Field	CC60SL							
		Type	rwh							
FB _H	CCU6_CC60SRH Reset: 00_H Capture/Compare Shadow Register for Channel CC60 High	Bit Field	CC60SH							
		Type	rwh							
FC _H	CCU6_CC61SRL Reset: 00_H Capture/Compare Shadow Register for Channel CC61 Low	Bit Field	CC61SL							
		Type	rwh							
FD _H	CCU6_CC61SRH Reset: 00_H Capture/Compare Shadow Register for Channel CC61 High	Bit Field	CC61SH							
		Type	rwh							
FE _H	CCU6_CC62SRL Reset: 00_H Capture/Compare Shadow Register for Channel CC62 Low	Bit Field	CC62SL							
		Type	rwh							
FF _H	CCU6_CC62SRH Reset: 00_H Capture/Compare Shadow Register for Channel CC62 High	Bit Field	CC62SH							
		Type	rwh							
RMAP = 0, PAGE 1										
9A _H	CCU6_CC63RL Reset: 00_H Capture/Compare Register for Channel CC63 Low	Bit Field	CC63VL							
		Type	rh							
9B _H	CCU6_CC63RH Reset: 00_H Capture/Compare Register for Channel CC63 High	Bit Field	CC63VH							
		Type	rh							
9C _H	CCU6_T12PRL Reset: 00_H Timer T12 Period Register Low	Bit Field	T12PVL							
		Type	rwh							
9D _H	CCU6_T12PRH Reset: 00_H Timer T12 Period Register High	Bit Field	T12PVH							
		Type	rwh							
9E _H	CCU6_T13PRL Reset: 00_H Timer T13 Period Register Low	Bit Field	T13PVL							
		Type	rwh							
9F _H	CCU6_T13PRH Reset: 00_H Timer T13 Period Register High	Bit Field	T13PVH							
		Type	rwh							
A4 _H	CCU6_T12DTCL Reset: 00_H Dead-Time Control Register for Timer T12 Low	Bit Field	DTM							
		Type	rw							
A5 _H	CCU6_T12DTCH Reset: 00_H Dead-Time Control Register for Timer T12 High	Bit Field	0	DTR2	DTR1	DTR0	0	DTE2	DTE1	DTE0
		Type	r	rh	rh	rh	r	rw	rw	rw
A6 _H	CCU6_TCTR0L Reset: 00_H Timer Control Register 0 Low	Bit Field	CTM	CDIR	STE1 2	T12R	T12 PRE	T12CLK		
		Type	rw	rh	rh	rh	rw	rw		
A7 _H	CCU6_TCTR0H Reset: 00_H Timer Control Register 0 High	Bit Field	0		STE1 3	T13R	T13 PRE	T13CLK		
		Type	r		rh	rh	rw	rw		
FA _H	CCU6_CC60RL Reset: 00_H Capture/Compare Register for Channel CC60 Low	Bit Field	CC60VL							
		Type	rh							

Functional Description

Table 17 CAN Register Overview (cont'd)

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
DB _H	DATA0 Reset: 00 _H CAN Data Register 0	Bit Field	CD							
		Type	rwh							
DC _H	DATA1 Reset: 00 _H CAN Data Register 1	Bit Field	CD							
		Type	rwh							
DD _H	DATA2 Reset: 00 _H CAN Data Register 2	Bit Field	CD							
		Type	rwh							
DE _H	DATA3 Reset: 00 _H CAN Data Register 3	Bit Field	CD							
		Type	rwh							

3.2.4.14 OCDS Registers

The OCDS SFRs can be accessed in the mapped memory area (RMAP = 1).

Table 18 OCDS Register Overview

Addr	Register Name	Bit	7	6	5	4	3	2	1	0
RMAP = 1										
E9 _H	MMCR2 Reset: 1U_H Monitor Mode Control 2 Register	Bit Field	STMO DE	EXBC	DSUS P	MBCO N	ALTDI	MMEP	MMOD E	JENA
		Type	rw	rw	rw	rwh	rw	rwh	rh	rh
F1 _H	MMCR Reset: 00_H Monitor Mode Control Register	Bit Field	MEXIT _P	MEXIT	0	MSTE P	MRAM S_P	MRAM S	TRF	RRF
		Type	w	rwh	r	rw	w	rwh	rh	rh
F2 _H	MMSR Reset: 00_H Monitor Mode Status Register	Bit Field	MBCA M	MBCIN	EXBF	SWBF	HWB3 F	HWB2 F	HWB1 F	HWB0 F
		Type	rw	rwh	rwh	rwh	rwh	rwh	rwh	rwh
F3 _H	MMBPCR Reset: 00_H Breakpoints Control Register	Bit Field	SWBC	HWB3C		HWB2C		HWB1 C	HWB0C	
		Type	rw	rw		rw		rw	rw	
F4 _H	MMICR Reset: 00_H Monitor Mode Interrupt Control Register	Bit Field	DVEC T	DRET R	COMR ST	MSTS EL	MMUI E_P	MMUI E	RRIE_ P	RRIE
		Type	rwh	rwh	rwh	rh	w	rw	w	rw
F5 _H	MMDR Reset: 00_H Monitor Mode Data Transfer Register Receive	Bit Field	MMRR							
		Type	rh							
F6 _H	HWBPSR Reset: 00_H Hardware Breakpoints Select Register	Bit Field	0			BPSEL _P	BPSEL			
		Type	r			w	rw			
F7 _H	HWBPDR Reset: 00_H Hardware Breakpoints Data Register	Bit Field	HWBPxx							
		Type	rw							
EB _H	MMWR1 Reset: 00_H Monitor Work Register 1	Bit Field	MMWR1							
		Type	rw							

Functional Description

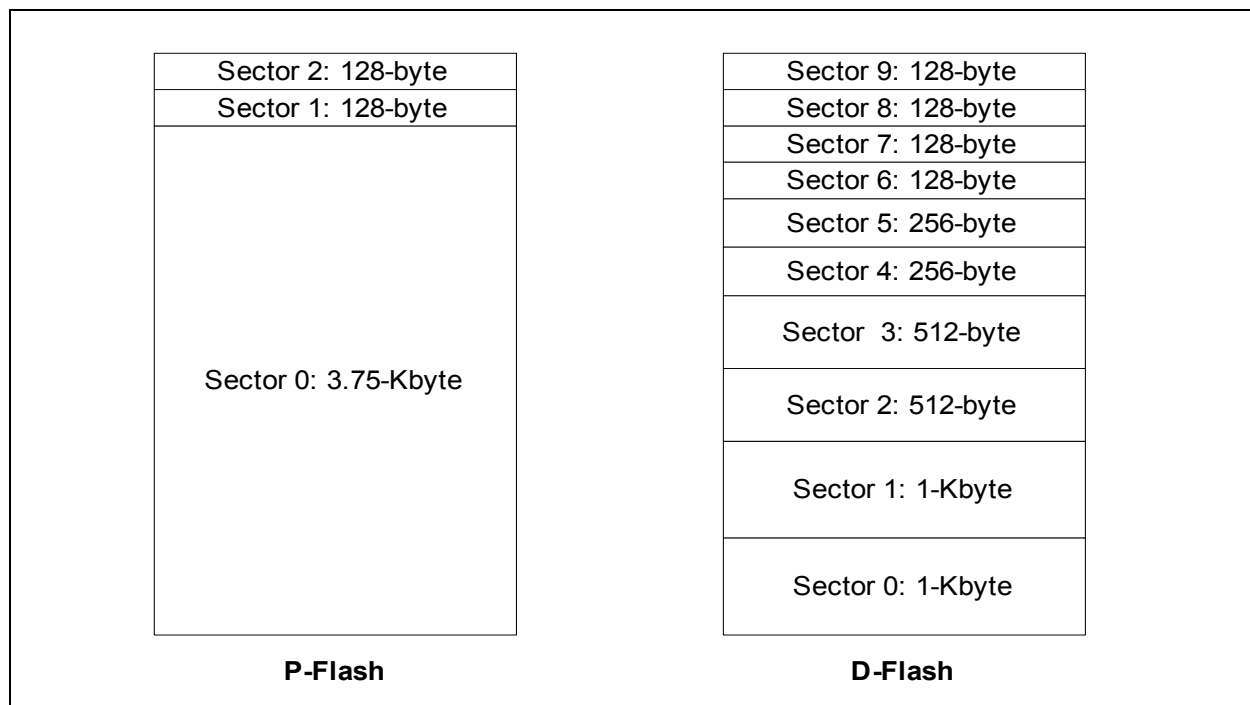


Figure 11 Flash Bank Sectorization

The internal structure of each Flash bank represents a sector architecture for flexible erase capability. The minimum erase width is always a complete sector, and sectors can be erased separately or in parallel. Contrary to standard EPROMs, erased Flash memory cells contain 0s.

The D-Flash bank is divided into more physical sectors for extended erasing and reprogramming capability; even numbers for each sector size are provided to allow greater flexibility and the ability to adapt to a wide range of application requirements.

3.3.2 Parallel Read Access of P-Flash

To enhance system performance, the P-Flash banks are configured for parallel read to allow two bytes of linear code to be read in 4 x CCLK cycles, compared to 6 x CCLK cycles if serial read is performed. This is achieved by reading two bytes in parallel from a P-Flash bank pair within the 3 x CCLK cycles access time and storing them in a cache. Subsequent read from the cache by the CPU does not require a wait state and can be completed within 1 x CCLK cycle. The result is the average instruction fetch time from the P-Flash banks is reduced and thus, the MIPS (Mega Instruction Per Second) of the system is increased.

However, if the parallel read feature is not desired due to certain timing constraints, it can be disabled by calling the parallel read disable subroutine.

Functional Description

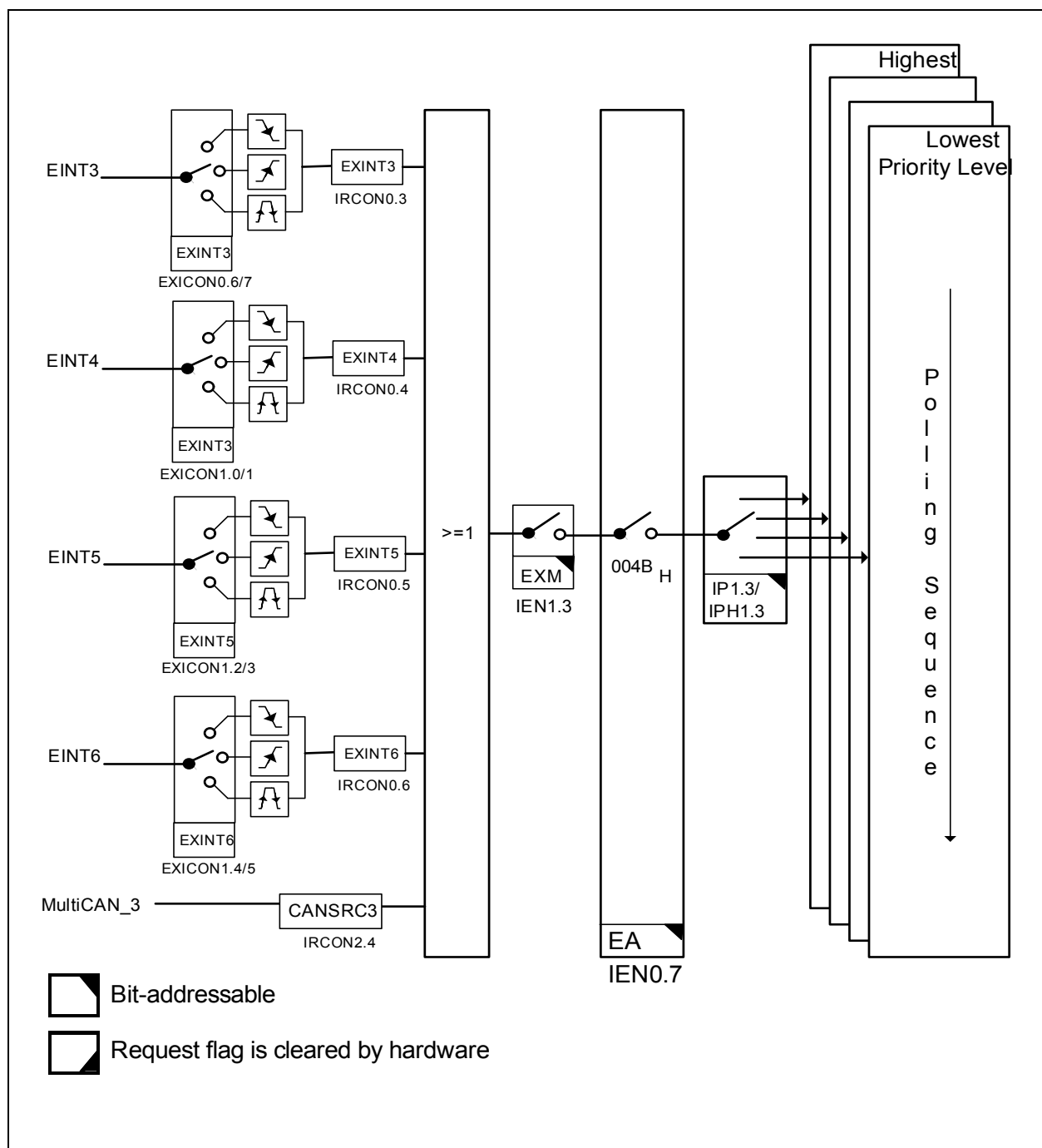


Figure 17 Interrupt Request Sources (Part 4)

Functional Description

3.4.3 Interrupt Priority

An interrupt that is currently being serviced can only be interrupted by a higher-priority interrupt, but not by another interrupt of the same or lower priority. Hence, an interrupt of the highest priority cannot be interrupted by any other interrupt request.

If two or more requests of different priority levels are received simultaneously, the request of the highest priority is serviced first. If requests of the same priority are received simultaneously, then an internal polling sequence determines which request is serviced first. Thus, within each priority level, there is a second priority structure determined by the polling sequence shown in [Table 21](#).

Table 21 Priority Structure within Interrupt Level

Source	Level
Non-Maskable Interrupt (NMI)	(highest)
External Interrupt 0	1
Timer 0 Interrupt	2
External Interrupt 1	3
Timer 1 Interrupt	4
UART Interrupt	5
Timer 2, UART Normal Divider Overflow, MultiCAN, LIN Interrupt	6
ADC, MultiCAN Interrupt	7
SSC Interrupt	8
External Interrupt 2, Timer 21, UART1, UART1 Normal Divider Overflow, MDU, CORDIC Interrupt	9
External Interrupt [6:3], MultiCAN Interrupt	10
CCU6 Interrupt Node Pointer 0, MultiCAN interrupt	11
CCU6 Interrupt Node Pointer 1, MultiCAN Interrupt	12
CCU6 Interrupt Node Pointer 2, MultiCAN Interrupt	13
CCU6 Interrupt Node Pointer 3, MultiCAN Interrupt	14

Functional Description

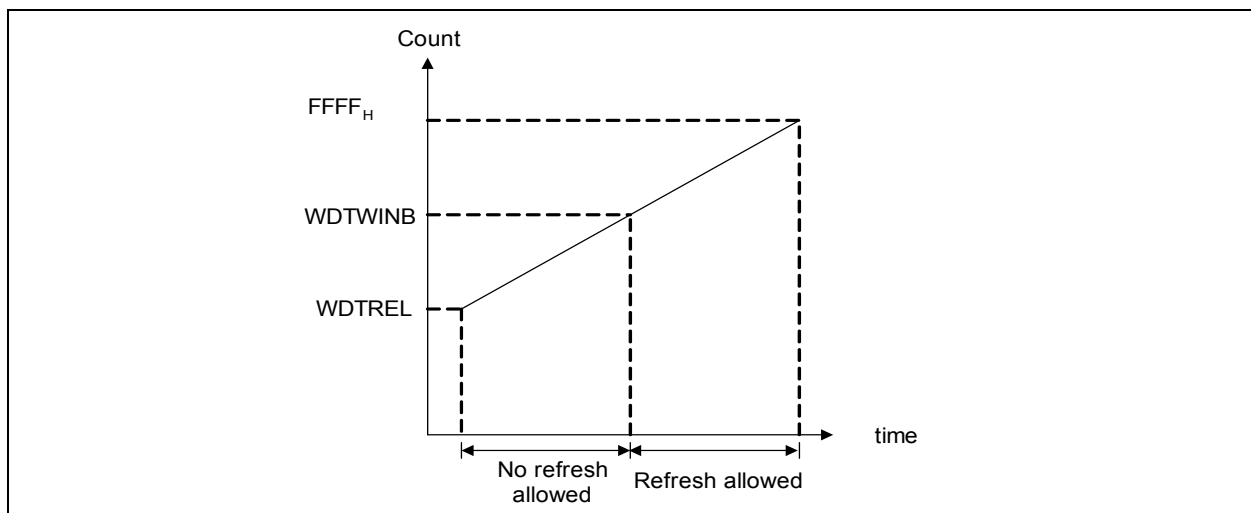


Figure 29 WDT Timing Diagram

Table 27 lists the possible watchdog time ranges that can be achieved using a certain module clock. Some numbers are rounded to 3 significant digits.

Table 27 Watchdog Time Ranges

Reload value In WDTREL	Prescaler for f_{PCLK}	
	2 (WDTIN = 0)	128 (WDTIN = 1)
	24 MHz	24 MHz
FF _H	21.3 μ s	1.37 ms
7F _H	2.75 ms	176 ms
00 _H	5.46 ms	350 ms

Functional Description

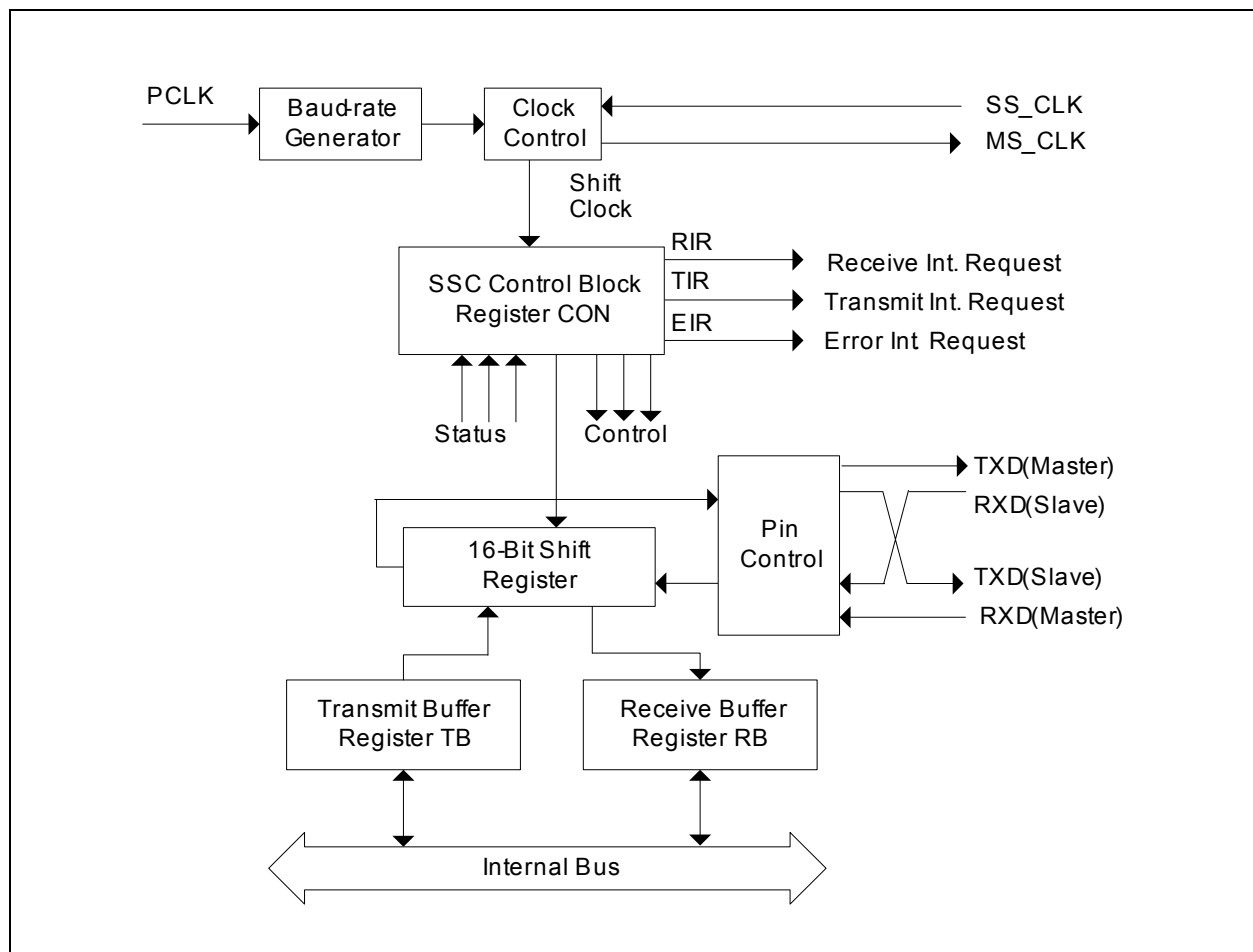


Figure 32 SSC Block Diagram

Functional Description

GLOBCTR. A prescaling ratio of 32 can be selected when the maximum performance of the ADC is not required.

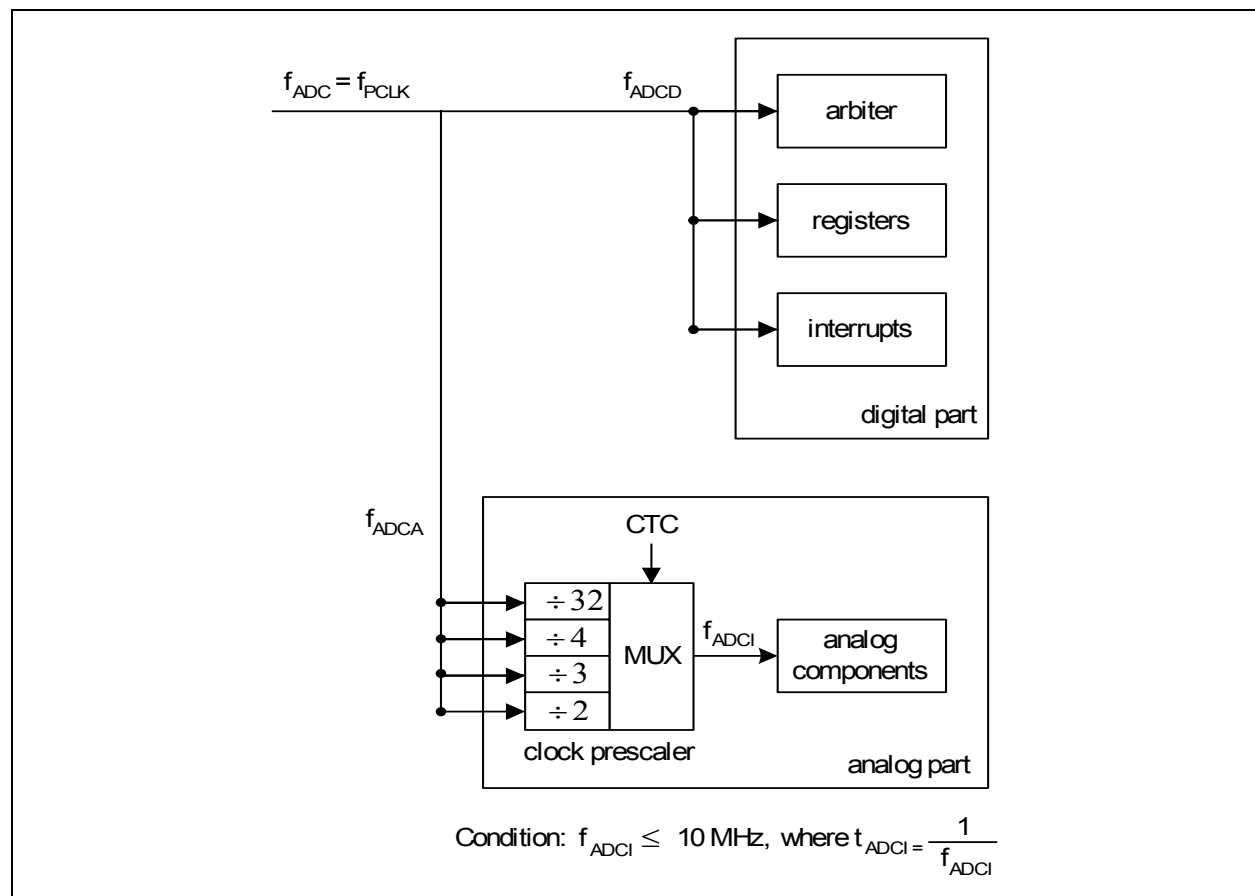


Figure 35 ADC Clocking Scheme

For module clock $f_{\text{ADC}} = 24 \text{ MHz}$, the analog clock f_{ADCI} frequency can be selected as shown in [Table 34](#).

Table 34 f_{ADCI} Frequency Selection

Module Clock f_{ADC}	CTC	Prescaling Ratio	Analog Clock f_{ADCI}
24 MHz	00 _B	÷ 2	12 MHz (N.A)
	01 _B	÷ 3	8 MHz
	10 _B	÷ 4	6 MHz
	11 _B (default)	÷ 32	750 kHz

As f_{ADCI} cannot exceed 10 MHz, bit field CTC should not be set to 00_B when f_{ADC} is 24 MHz. During slow-down mode where f_{ADC} may be reduced to 12 MHz, 6 MHz etc., CTC can be set to 00_B as long as the divided analog clock f_{ADCI} does not exceed 10 MHz.

Functional Description
Table 36 Chip Identification Number (cont'd)

Product Variant	Chip Identification Number		
	AA-Step	AB-Step	AC-Step
XC886-6FFA 3V3	-	095D1562 _H	0B5D1562 _H
XC888-6FFA 3V3	-	095D1563 _H	0B5D1563 _H
XC886CLM-8FFA 5V	-	09900102 _H	0B900102 _H
XC888CLM-8FFA 5V	-	09900103 _H	0B900103 _H
XC886LM-8FFA 5V	-	09900122 _H	0B900122 _H
XC888LM-8FFA 5V	-	09900123 _H	0B900123 _H
XC886CLM-6FFA 5V	-	09951502 _H	0B951502 _H
XC888CLM-6FFA 5V	-	09951503 _H	0B951503 _H
XC886LM-6FFA 5V	-	09951522 _H	0B951522 _H
XC888LM-6FFA 5V	-	09951523 _H	0B951523 _H
XC886CM-8FFA 5V	-	09980102 _H	0B980102 _H
XC888CM-8FFA 5V	-	09980103 _H	0B980103 _H
XC886C-8FFA 5V	-	09980142 _H	0B980142 _H
XC888C-8FFA 5V	-	09980143 _H	0B980143 _H
XC886-8FFA 5V	-	09980162 _H	0B980162 _H
XC888-8FFA 5V	-	09980163 _H	0B980163 _H
XC886CM-6FFA 5V	-	099D1502 _H	0B9D1502 _H
XC888CM-6FFA 5V	-	099D1503 _H	0B9D1503 _H
XC886C-6FFA 5V	-	099D1542 _H	0B9D1542 _H
XC888C-6FFA 5V	-	099D1543 _H	0B9D1543 _H
XC886-6FFA 5V	-	099D1562 _H	0B9D1562 _H
XC888-6FFA 5V	-	099D1563 _H	0B9D1563 _H

ROM Devices

XC886CLM-8RFA 3V3	22400502 _H	-	-
XC888CLM-8RFA 3V3	22400503 _H	-	-
XC886LM-8RFA 3V3	22400522 _H	-	-
XC888LM-8RFA 3V3	22400523 _H	-	-
XC886CLM-6RFA 3V3	22411502 _H	-	-
XC888CLM-6RFA 3V3	22411503 _H	-	-

4 Electrical Parameters

Chapter 4 provides the characteristics of the electrical parameters which are implementation-specific for the XC886/888.

4.1 General Parameters

The general parameters are described here to aid the users in interpreting the parameters mainly in [Section 4.2](#) and [Section 4.3](#).

4.1.1 Parameter Interpretation

The parameters listed in this section represent partly the characteristics of the XC886/888 and partly its requirements on the system. To aid interpreting the parameters easily when evaluating them for a design, they are indicated by the abbreviations in the "Symbol" column:

- **CC**
These parameters indicate **C**ontroller **C**haracteristics, which are distinctive features of the XC886/888 and must be regarded for a system design.
- **SR**
These parameters indicate **S**ystem **R**equirements, which must be provided by the microcontroller system in which the XC886/888 is designed in.

Electrical Parameters
Table 38 Input/Output Characteristics (Operating Conditions apply) (cont'd)

Parameter	Symbol		Limit Values		Unit	Test Conditions
			min.	max.		
Maximum current out of V_{SS}	I_{MVSS}	SR	–	120	mA	³⁾
$V_{DDP} = 3.3 \text{ V Range}$						
Output low voltage	V_{OL}	CC	–	1.0	V	$I_{OL} = 8 \text{ mA}$
			–	0.4	V	$I_{OL} = 2.5 \text{ mA}$
Output high voltage	V_{OH}	CC	$V_{DDP} - 1.0$	–	V	$I_{OH} = -8 \text{ mA}$
			$V_{DDP} - 0.4$	–	V	$I_{OH} = -2.5 \text{ mA}$
Input low voltage on port pins (all except P0.0 & P0.1)	V_{ILP}	SR	–	$0.3 \times V_{DDP}$	V	CMOS Mode
Input low voltage on P0.0 & P0.1	V_{ILP0}	SR	-0.2	$0.3 \times V_{DDP}$	V	CMOS Mode
Input low voltage on RESET pin	V_{ILR}	SR	–	$0.3 \times V_{DDP}$	V	CMOS Mode
Input low voltage on TMS pin	V_{ILT}	SR	–	$0.3 \times V_{DDP}$	V	CMOS Mode
Input high voltage on port pins (all except P0.0 & P0.1)	V_{IHP}	SR	$0.7 \times V_{DDP}$	–	V	CMOS Mode
Input high voltage on P0.0 & P0.1	V_{IHP0}	SR	$0.7 \times V_{DDP}$	V_{DDP}	V	CMOS Mode
Input high voltage on RESET pin	V_{IHR}	SR	$0.7 \times V_{DDP}$	–	V	CMOS Mode
Input high voltage on TMS pin	V_{IHT}	SR	$0.75 \times V_{DDP}$	–	V	CMOS Mode
Input Hysteresis	HYS	CC	$0.03 \times V_{DDP}$	–	V	CMOS Mode ¹⁾
Input Hysteresis on XTAL1	$HYSX$	CC	$0.07 \times V_{DDC}$	–	V	¹⁾
Input low voltage at XTAL1	V_{ILX}	SR	$V_{SS} - 0.5$	$0.3 \times V_{DDC}$	V	

Electrical Parameters

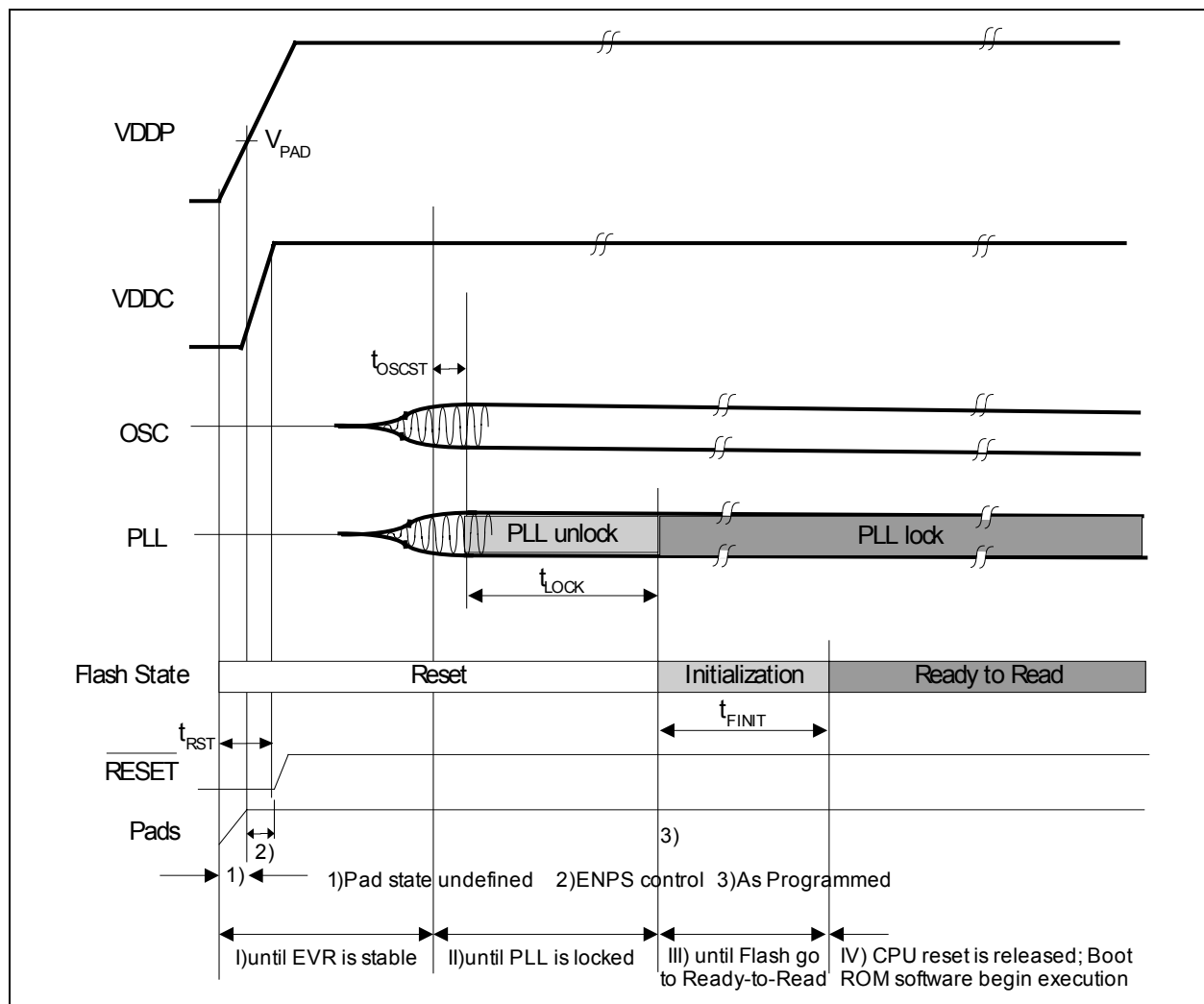


Figure 44 Power-on Reset Timing

Electrical Parameters
4.3.5 External Clock Drive XTAL1

Table 48 shows the parameters that define the external clock supply for XC886/888. These timing parameters are based on the direct XTAL1 drive of clock input signals. They are not applicable if an external crystal or ceramic resonator is considered.

Table 48 External Clock Drive Characteristics (Operating Conditions apply)

Parameter	Symbol		Limit Values		Unit	Test Conditions
			Min.	Max.		
Oscillator period	t_{osc}	SR	83.3	250	ns	1)2)
High time	t_1	SR	25	-	ns	2)3)
Low time	t_2	SR	25	-	ns	2)3)
Rise time	t_3	SR	-	20	ns	2)3)
Fall time	t_4	SR	-	20	ns	2)3)

1) The clock input signals with 45-55% duty cycle are used.

2) Not all parameters are 100% tested, but are verified by design/characterization and test correlation.

3) The clock input signal must reach the defined levels V_{ILX} and V_{IHx} .

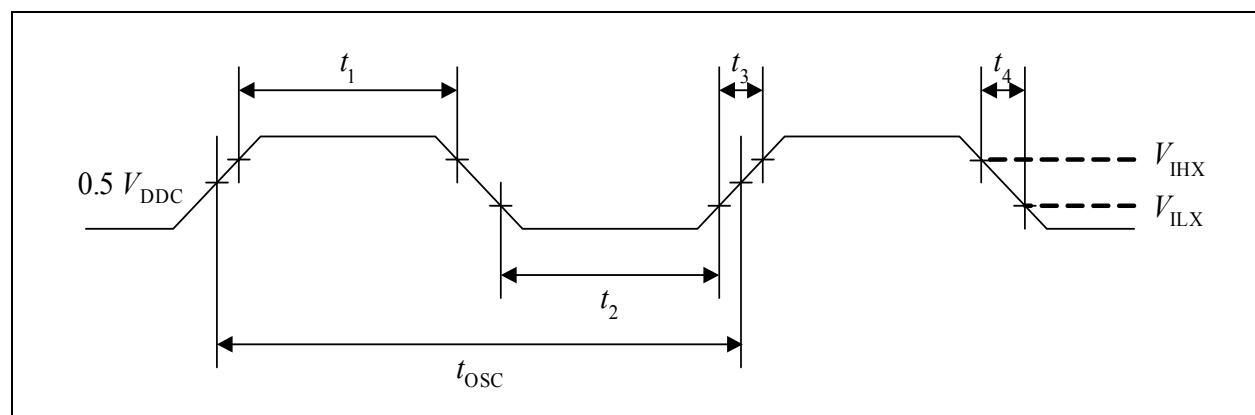


Figure 45 External Clock Drive XTAL1

Package and Quality Declaration
5.3 Quality Declaration

Table 2 shows the characteristics of the quality parameters in the XC886/888.

Table 2 Quality Parameters

Parameter	Symbol	Limit Values		Unit	Notes
		Min.	Max.		
ESD susceptibility according to Human Body Model (HBM)	V_{HBM}	-	2000	V	Conforming to EIA/JESD22-A114-B ¹⁾
ESD susceptibility according to Charged Device Model (CDM) pins	V_{CDM}	-	500	V	Conforming to JESD22-C101-C ¹⁾

1) Not all parameters are 100% tested, but are verified by design/characterization and test correlation.